



# **DUAL PROCESSOR SUPERVISORS**

#### **FEATURES**

- . Dual Supervisory Circuits for DSP- and **Processor-Based Systems**
- **Power-On Reset Generator with Fixed Delay** Time of 200ms; no External Capacitor Needed
- Watchdog Timer Retriggers the RESET Output at SENSEn ≥ V<sub>IT+</sub>
- **Temperature-Compensated Voltage Reference**
- Maximum Supply Current of 40µA
- Supply Voltage Range: 2.7V to 6V
- Defined RESET Output From V<sub>DD</sub> ≥ 1.1V
- **MSOP-8 and SO-8 Packages**
- Temperature Range: -40°C to +85°C

### **APPLICATIONS**

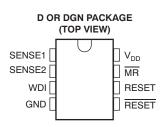
- **Processor Supply Monitoring**
- **Industrial Equipment**
- **Automotive Systems**
- Portable/Battery-Powered Equipment
- **Wireless Communication Systems**
- **Notebook/Desktop Computers**

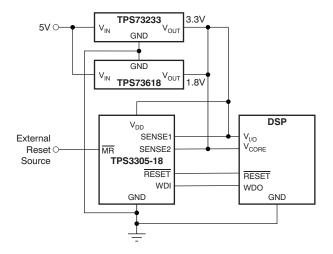
# DESCRIPTION

The TPS3305 family is a series of micropower supply voltage supervisors designed for circuit initialization. Its dual monitor topology is well-suited to use in DSP and processor-based systems, which often require two supply voltages, core and I/O.

RESET is asserted when the voltage at either SENSEn pin falls below its threshold voltage, VIT. When both SENSEn pins are again above their respective threshold voltages, RESET is held low for the factory-programmed delay time (200ms typ). RESET is also asserted if the watchdog input (WDI) is not toggled for more than 1.6s typ.

The TPS3305-xx devices are available in either 8-pin MSOP or SO packages, and are specified for operation over a temperature range of -40°C to +85°C.





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### ORDERING INFORMATION(1)

	NOMINAL SUPER	RVISED VOLTAGE	THRESHOLD VOLTAGE (TYP)			
DEVICE	SENSE1	SENSE2	SENSE1	SENSE2		
TPS3305-18	3.3 V	1.8 V	2.93 V	1.68 V		
TPS3305-25	3.3 V	2.5 V	2.93 V	2.25 V		
TPS3305-33	5.0 V	3.3 V	4.55 V	2.93 V		

<sup>(1)</sup> For the most current specifications and package information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

# **ABSOLUTE MAXIMUM RATINGS**(1)(2)

Over operating junction temperature range (unless otherwise noted).

	UNIT
Supply voltage range, V <sub>DD</sub>	-0.3V to +7V
$V_{MR}, V_{WDI}$	$-0.3V$ to $V_{DD}$ + $0.3V$
Input voltage at SENSE1 and SENSE2, V <sub>I</sub>	$(V_{DD} + 0.3)V_{IT} / 1.25V$
V <sub>RESET</sub> , V <sub>RESET</sub>	-0.3V to +7V
Maximum low output current, I <sub>OL</sub>	5mA
Maximum high output current, I <sub>OH</sub>	–5mA
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{DD}$ )	±20mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{DD}$ )	±20mA
Continuous total power dissipation	See Dissipation Ratings Table
Operating junction temperature range, T <sub>J</sub>	-40°C to +85°C
Storage temperature range, T <sub>stg</sub>	−65°C to +150°C
Soldering temperature	+260°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### **DISSIPATION RATINGS TABLE**

PACKAGE	T <sub>A</sub> ≤ +25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = +25°C	T <sub>A</sub> = +70°C POWER RATING	T <sub>A</sub> = +85°C POWER RATING		
DGN	2.14W	17.1mW/°C	1.37W	1.11W		
D	725mW	5.8mW/°C	464mW	377mW		

Product Folder Link(s): TPS3305

<sup>(2)</sup> All voltage values are with respect to GND.



### **ELECTRICAL CHARACTERISTICS**

Over operating junction temperature range (unless otherwise noted).

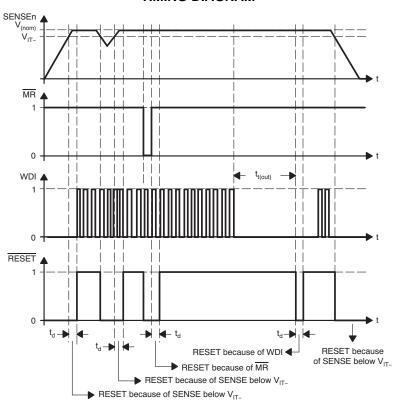
				TPS	3305-xx		
	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{DD}$	Input supply range			2.7		6.0	V
T <sub>J</sub>	Operating junction temperature ra	ange		-40		+85	°C
			$V_{DD} = 2.7V \text{ to } 6V,$ $I_{OH} = -20\mu\text{A}$	V <sub>DD</sub> - 0.2V			V
V <sub>OH</sub>	High-level output voltage		$V_{DD} = 3.3V, I_{OH} = -2mA$	V <sub>DD</sub> - 0.4V	2.7 6.0 -40 +85 -2V -40 -85 -2V -4V -4V -4V -4V -64 -64 -68 1.72 -20 2.25 2.30 -86 2.93 3.02 -46 4.55 4.64 -64 1.68 1.73 -20 2.25 2.32 -86 2.93 3.02 -46 4.55 4.67 -15 20 -30 40 -10 150 -15 -20 -130 -180 -5 8		V
			$V_{DD} = 6V$ , $I_{OH} = -3mA$	V <sub>DD</sub> - 0.4V			V
			$V_{DD} = 2.7V \text{ to 6V},$ $I_{OL} = 20\mu\text{A}$			0.2	V
$V_{OL}$	Low-level output voltage		$V_{DD} = 3.3V, I_{OL} = 2mA$			0.4	V
			$V_{DD} = 6V$ , $I_{OL} = 3mA$			0.4	V
	Power-up reset voltage <sup>(1)</sup>		$V_{DD} \ge 1.1V, I_{OL} = 20\mu A$			0.4 V 0.4 V 1.72 V 2.30 V 3.0 V 4.64 V 1.73 V 2.32 V 3.02 V 4.67 V m' m'	V
				1.64	1.68	1.72	V
		VSENSE1,	$V_{DD} = 2.7V \text{ to } 6V,$	2.20	2.25	2.30	V
		VSENSE2	$T_A = 0$ °C to +85°C	2.86	2.93	3.0	V
	Negative-going input threshold			4.46	4.55	4.64	V
$V_{IT-}$	voltage <sup>(2)</sup>			1.64	1.68	1.73	V
		VSENSE1,	$V_{DD} = 2.7V \text{ to } 6V,$	2.20	2.25	2.32	V
		VSENSE2	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	2.86	2.93	1.73 2.32 3.02	V
				4.46	4.55		V
			V <sub>IT</sub> = 1.68V		15		V           mV           mV
			V <sub>IT</sub> = 2.25V		20		mV
$V_{hys}$	Hysteresis at VSENSEn input		V <sub>IT</sub> = 2.93V		30		mV
			V <sub>IT</sub> = 4.55V		40		mV
I <sub>H(AV)</sub>	Average high-level input current	WDI	WDI = $V_{DD}$ = 6V Time average (dc = 88%)		100	150	μΑ
$I_{L(AV)}$	Average low-level input current	WDI	WDI = 0V, $V_{DD}$ = 6V Time average (dc = 12%)		-15	-20	μΑ
V <sub>IH</sub>	High-level input voltage at $\overline{MR}$ ar			0.7 x V <sub>DD</sub>			V
$V_{IL}$	Low-level input voltage at MR an	d WDI			(	0.3 x V <sub>DD</sub>	V
Δt / ΔV	Input transition rise and fall rate a	at MR				-20 0.3 x V <sub>DD</sub> 50 170 -180	ns/V
		WDI	$WDI = V_{DD} = 6V$		120	170	μΑ
	High lovel input access	MR	$\overline{MR} = 0.7 \times V_{DD}, V_{DD} = 6V$		-130	-180	μΑ
I <sub>H</sub>	High-level input current	SENSE1	VSENSE1 = V <sub>DD</sub> = 6V		5	8	μΑ
		SENSE2	VSENSE2 = V <sub>DD</sub> = 6V		6	+85  0.2  0.4  0.4  0.4  1.72  2.30  3.0  4.64  1.73  2.32  3.02  4.67  150  -20  3 × V <sub>DD</sub> 50  170  -180	μΑ
		WDI	$WDI = 0V, V_{DD} = 6V$		-120	-170	μΑ
IL	Low-level input current	MR	$\overline{MR} = 0V, V_{DD} = 6V$		-430	-600	μΑ
		SENSEn	VSENSE1,2 = 0V	-1		1	μΑ
I <sub>DD</sub>	Supply current	I				40	<u>.</u> μΑ
Cı	Input capacitance		$V_I = 0V \text{ to } V_{DD}$		10	рF	•

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 <sup>(1)</sup> The lowest supply voltage at which RESET becomes active. t<sub>r</sub>, V<sub>DD</sub> ≥15 μs/V.
 (2) To ensure best stability of the threshold voltage, a bypass capacitor (0.1 μF ceramic) should be placed close to the supply terminals.







# **TIMING REQUIREMENTS**

At  $V_{DD}$  = 2.7V to 6V,  $R_L$  = 1M $\Omega$ ,  $C_L$  = 50pF, and  $T_J$  = +25°C.

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
		SENSEn	$V_{SENSEnL} = V_{IT-} -0.2V$ , $V_{SENSEnH} = V_{IT+} +0.2V$	6			μs
t <sub>w</sub>	Pulse width	MR	V 07×V V 02×V	100			ns
	VV	WDI	$V_{IH} = 0.7 \times V_{DD}, V_{IL} = 0.3 \times V_{DD}$	100			ns

### **SWITCHING CHARACTERISTICS**

At  $V_{DD}$  = 2.7V to 6V,  $R_L$  = 1M $\Omega$ ,  $C_L$  = 50pF, and  $T_J$  = +25°C.

	PARAMETEI	र	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>t(out)</sub>	Watchdog time-out	$\begin{array}{c} V_{I(SENSEn)} \geq V_{IT+} + 0.2V,  \overline{MR}  \geq 0.7  \times \\ V_{DD} \\ See  \overline{\text{Timing Diagram}} \end{array}$				2.3	s
t <sub>d</sub>	Delay time		$V_{I(SENSEn)} \ge V_{IT+} + 0.2V, \overline{MR} \ge 0.7 \times V_{DD}$ See Timing Diagram	140	200	280	ms
t <sub>PHL</sub>	Propagation (delay) time, high-to-low level output	MR to RESET, MR to RESET	$V_{I(SENSEn)} \ge V_{IT+} + 0.2V,$ $V_{IH} = 0.7 \times V_{DD}, V_{IL} = 0.3 \times V_{DD}$		200	500	ns
t <sub>PLH</sub>	Propagation (delay) time, low-to-high level output	MR to RESET, MR to RESET	$V_{I(SENSEn)} \ge V_{IT+} + 0.2V,$ $V_{IH} = 0.7 \times V_{DD}, V_{IL} = 0.3 \times V_{DD}$		200	500	ns
t <sub>PHL</sub>	Propagation (delay) time, high-to-low level output	SENSEn to RESET, SENSEn to RESET	$\frac{V_{IH}}{MR} = V_{IT+} + 0.2V, V_{IL} = V_{IT-} -0.2V,$ $\frac{V_{IH}}{MR} \ge 0.7 \times V_{DD}$		1	5	μs
t <sub>PLH</sub>	Propagation (delay) time, low-to-high level output	SENSEn to RESET, SENSEn to RESET	$\frac{V_{IH}=V_{IT+}+0.2V,\ V_{IL}=V_{IT-}\ -0.2V,}{\overline{MR}\geq 0.7\times V_{DD}}$		1	5	μs

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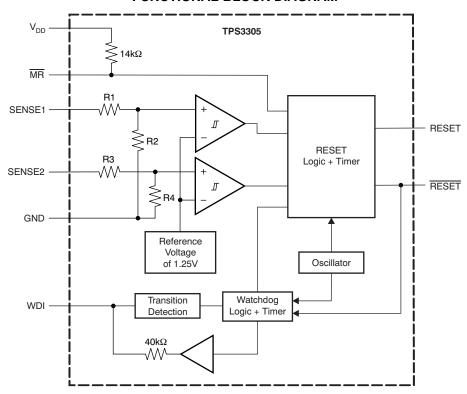
### **DEVICE INFORMATION**

# **FUNCTION/TRUTH TABLE**(1)

MR	SENSE1 > V <sub>IT1</sub>	SENSE2 > V <sub>IT2</sub>	RESET	RESET
L	X	X	L	Н
Н	0	0	L	Н
Н	0	1	L	Н
Н	1	0	L	Н
Н	1	1	Н	L

#### (1) X = Don't care

### **FUNCTIONAL BLOCK DIAGRAM**

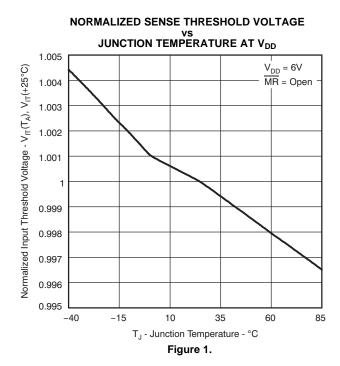


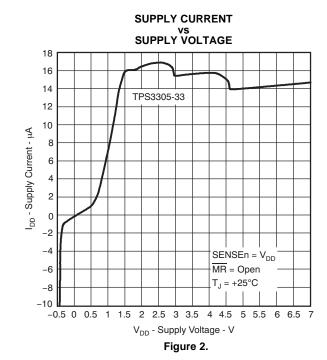
### **TERMINAL FUNCTIONS**

TEI	RMINAL	
NAME	NO.	DESCRIPTION
GND	4	Ground
MR	7	Manual reset
RESET	5	Active-low reset output
RESET	6	Active-high reset output
SENSE1	1	Sense voltage input 1
SENSE2	2	Sense voltage input 2
WDI	3	Watchdog timer input
V <sub>DD</sub>	8	Supply voltage

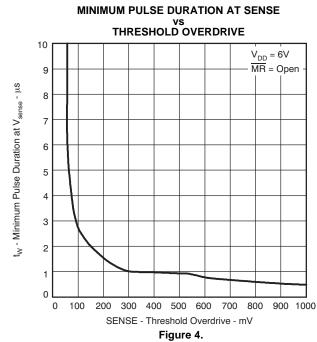


### **TYPICAL CHARACTERISTICS**



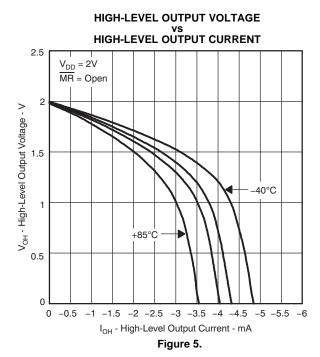


# INPUT CURRENT vs INPUT VOLTAGE AT $\overline{\text{MR}}$ 100 $V_{DD} = 6V$ $T_J = +25^{\circ}C$ 0 -100 -200 I<sub>1</sub> - Input Current - μA -300 -400 -500 -600 -700 -800 -900 -1 -0.5 0 0.5 1 1.5 2 2.5 3 3.5 4 4.5 5 5.5 6 6.5 $V_I$ - Input Voltage at $\overline{MR}$ - V Figure 3.





# **TYPICAL CHARACTERISTICS (continued)**



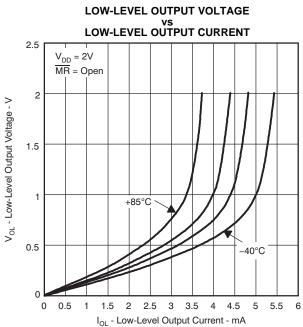
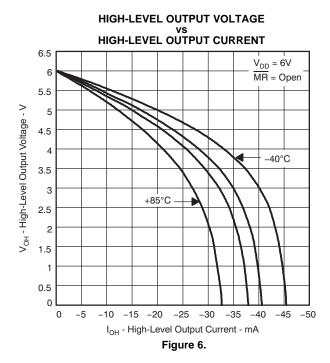
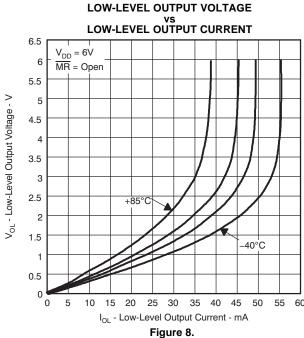


Figure 7.









6-Feb-2020

### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
TPS3305-18D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	30518	Sample
TPS3305-18DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	30518	Sample
TPS3305-18DGN	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAM	Sample
TPS3305-18DGNG4	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAM	Sample
TPS3305-18DGNR	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAM	Sample
TPS3305-18DGNRG4	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAM	Sample
TPS3305-18DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	30518	Sample
TPS3305-18DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	30518	Sample
TPS3305-25D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	30525	Sample
TPS3305-25DGN	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAN	Sample
TPS3305-25DGNR	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAN	Sample
TPS3305-25DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	30525	Sample
TPS3305-33D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	30533	Sample
TPS3305-33DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	30533	Sample
TPS3305-33DGN	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAO	Sample
TPS3305-33DGNG4	ACTIVE	HVSSOP	DGN	8	80	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAO	Sample
TPS3305-33DGNR	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAO	Sample



# **PACKAGE OPTION ADDENDUM**

6-Feb-2020

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS3305-33DGNRG4	ACTIVE	HVSSOP	DGN	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AAO	Samples
TPS3305-33DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	30533	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION





		Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
		Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
ľ	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3305-18DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS3305-18DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS3305-25DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS3305-25DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS3305-33DGNR	HVSSOP	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TPS3305-33DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

www.ti.com 6-Sep-2019



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3305-18DGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TPS3305-18DR	SOIC	D	8	2500	350.0	350.0	43.0
TPS3305-25DGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TPS3305-25DR	SOIC	D	8	2500	350.0	350.0	43.0
TPS3305-33DGNR	HVSSOP	DGN	8	2500	358.0	335.0	35.0
TPS3305-33DR	SOIC	D	8	2500	350.0	350.0	43.0



SMALL OUTLINE INTEGRATED CIRCUIT



## NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



#### NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DGN (S-PDSO-G8)

# PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <a href="https://www.ti.com">www.ti.com</a>.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Falls within JEDEC MO-187 variation AA-T

### PowerPAD is a trademark of Texas Instruments.



# $\textbf{PowerPAD}^{^{\text{\tiny{TM}}}}\,\textbf{VSSOP - 1.1 mm max height}$

SMALL OUTLINE PACKAGE



### NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187.



SMALL OUTLINE PACKAGE



#### NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
- 9. Size of metal pad may vary due to creepage requirement.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 11. Board assembly site may have different recommendations for stencil design.



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